

# Cascadable Silicon Bipolar MMIC Amplifier

## Technical Data

#### **MSA-0685**

#### **Features**

- Cascadable 50  $\Omega$  Gain Block
- Low Operating Voltage:  $3.5 \text{ V Typical V}_{d}$
- 3 dB Bandwidth: DC to 0.8 GHz
- **High Gain:** 18.5 dB Typical at 0.5 GHz
- Low Noise Figure: 3.0 dB Typical at 0.5 GHz
- Low Cost Plastic Package

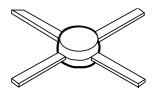
#### **Description**

The MSA-0685 is a high performance silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a low cost

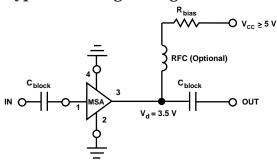
plastic package. This MMIC is designed for use as a general purpose  $50~\Omega$  gain block. Typical applications include narrow and broad band IF and RF amplifiers in commercial and industrial applications.

The MSA-series is fabricated using HP's 10 GHz f<sub>T</sub>, 25 GHz f<sub>MAX</sub>, silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

#### 85 Plastic Package



#### **Typical Biasing Configuration**



5965-9587E 6-378

MSA-0685 Absolute Maximum Ratings

Parameter	Absolute Maximum <sup>[1]</sup>
Device Current	50 mA
Power Dissipation <sup>[2,3]</sup>	200 mW
RF Input Power	+13dBm
Junction Temperature	150°C
Storage Temperature	−65 to 150°C

Thermal Resistance $^{[2,4]}$ :						
$\theta_{\rm jc} = 110$ °C/W						

#### **Notes:**

- 1. Permanent damage may occur if any of these limits are exceeded.
- 2.  $T_{CASE} = 25$ °C.
- 3. Derate at 9.1 mW/°C for  $T_{\rm C} > 128$  °C.
- 4. See MEASUREMENTS section "Thermal Resistance" for more information.

# Electrical Specifications<sup>[1]</sup>, $T_A = 25$ °C

Symbol	Parameters and Test Conditions: 1	Units	Min.	Тур.	Max.	
GP	Power Gain ( $ S_{21} ^2$ )	f = 0.1  GHz	dB		20.0	
		f = 0.5  GHz		17.0	18.5	
$\Delta G_{P}$	Gain Flatness	f = 0.1 to 0.5 GHz	dB		± 0.7	
f <sub>3 dB</sub>	3 dB Bandwidth		GHz		0.8	
VSWR	Input VSWR	f = 0.1  to  1.5  GHz			1.5:1	
VOVIL	Output VSWR	f = 0.1  to  1.5  GHz			1.4:1	
NF	$50~\Omega$ Noise Figure	f = 0.5  GHz	dB		3.0	
P <sub>1 dB</sub>	Output Power at 1 dB Gain Compression	f = 0.5  GHz	dBm		2.0	
IP3	Third Order Intercept Point	f = 0.5  GHz	dBm		14.5	
$t_{\mathrm{D}}$	Group Delay	f = 0.5  GHz	psec		200	
$V_{d}$	Device Voltage		V	2.8	3.5	4.2
dV/dT	Device Voltage Temperature Coefficient		mV/°C		-8.0	

#### Note:

<sup>1.</sup> The recommended operating current range for this device is 12 to 25 mA. Typical performance as a function of current is on the following page.

MSA-0685 Typical Scattering	g Parameters	$(\mathbf{Z} = 50 \Omega, \mathbf{T})$	$_{A} = 25^{\circ}\text{C}, I_{d} = 16 \text{ mA})$

Freq. S <sub>11</sub>		$S_{21}$		$\mathbf{S}_{12}$			$\mathbf{S}_{22}$				
GHz	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang	k
0.1	.04	171	20.1	10.09	171	-22.5	.075	5	.04	-30	1.04
0.2	.02	-180	29.8	9.75	161	-22.4	.076	10	.05	<b>-</b> 56	1.04
0.3	.02	<b>-</b> 143	19.4	9.38	153	-22.2	.077	15	.07	<b>-</b> 76	1.05
0.4	.03	-113	19.1	8.99	145	-21.8	.081	17	.08	<b>-</b> 91	1.04
0.5	.05	-105	18.7	8.57	138	-21.3	.086	21	.10	-104	1.04
0.6	.07	-101	18.2	8.14	131	-20.7	.092	25	.11	-116	1.03
0.8	.10	-111	17.3	7.32	119	-19.7	.103	28	.13	-134	1.01
1.0	.13	-118	16.4	6.57	107	-18.8	.115	28	.14	-150	0.99
1.5	.21	<b>-</b> 140	14.1	5.06	84	-17.1	.140	28	.15	180	1.00
2.0	.29	-163	12.0	3.98	65	-15.8	.163	26	.16	157	1.02
2.5	.34	-176	10.3	3.26	55	-15.2	.174	28	.16	150	1.06
3.0	.41	169	8.7	2.71	42	-14.8	.181	25	.15	143	1.10
3.5	.46	157	7.2	2.31	30	-14.2	.194	22	.13	144	1.11
4.0	.49	146	6.1	2.01	18	-13.8	.203	20	.10	156	1.13
4.5	.52	135	5.0	1.77	7	-13.4	.215	17	.09	173	1.14
5.0	.54	123	4.1	1.60	-3	-12.9	.226	15	.09	-178	1.14

#### Note:

 $1. \ \ A$  model for this device is available in the DEVICE MODELS section.

# Typical Performance, $T_A = 25^{\circ}C$

(unless otherwise noted)

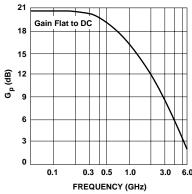


Figure 1. Typical Power Gain vs. Frequency,  $T_A$  = 25°C,  $I_d$  = 16 mA.

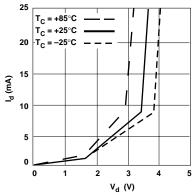


Figure 2. Device Current vs. Voltage.

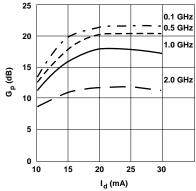


Figure 3. Power Gain vs. Current.

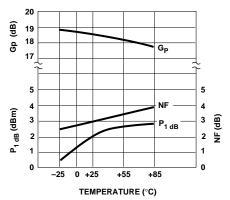


Figure 4. Output Power at 1 dB Gain Compression, NF and Power Gain vs. Case Temperature, f=0.5~GHz,  $I_d=16mA$ .

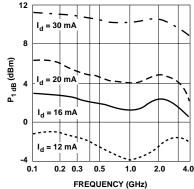


Figure 5. Output Power at 1 dB Gain Compression vs. Frequency.

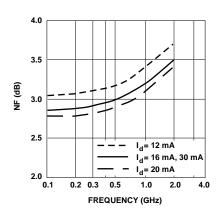


Figure 6. Noise Figure vs. Frequency.

### **85 Plastic Package Dimensions**

